

140 Commerce Drive

2N3375 140 Commerce Dive Montgomeryville, PA 1893 Tel: (215) 631-9840 2N3632/2N3733

RF & MICROWAVE TRANSISTORS VHF-UHF CLASS C WIDE BAND

■ FREQUENCY

130 TO 400MHz

VOLTAGE

28V

POWER OUT

2.5 TO 13.5W

- HIGH POWER GAIN
- HIGH EFFICIENCY
- CLASS C TRANSISTORS
- COMMON EMITTER



TO 60 (M137)

ORDER CODE

SD1050 SD1070 SD1075

BRANDING

2N3375 2N3632 2N3733

DESCRIPTION

This line of silicon epitaxial NPN planar high frequency transistors employs a multi emitter electrode design. This feature together with a heavily diffused base matrix located between the individual emitters results in high RF current handling capability, high power gain, low base resistance and low output capacitance. These transistors are intended for Class A, B, or C amplifier, oscillator or frequency multiplier circuits and are specifically designed for operation in the VHF-UHF region.

Device	Package
2N3375	TO 60
2N3632	TO 60
2N3733	TO 60

PIN CONNECTION



S882N3375-01

1 emitter 2 base

3 collector

March 1989

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2N3375/2N3632/2N3733

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

Symbol	Parameter	2N3375	2N3632	2N3733	Unit
V _{CBO}	Collector to Base Voltage	65	65	65	٧
V _{CEO}	Collector to Emitter Voltage	40	40	40	٧
VEBO	Emitter to Base Voltage	4.0	4.0	4.0	٧
I _{C (max)}	Continuous Collector Current	1.5	3.0	3.0	Α
PD	Total Dissipation at 25°C Stud	11.6	23.0	23.0	٧
Ti	Junction Temperature	200	200	200	°C
Tsta	Storage Temperature	- 65 to 150	- 65 to 150	- 65 to 150	°C

		2N3375	2N3632	2N3733	
R _{th(i-c)}	Junction-case Thermal Resistance	15.0	7.6	7.6	°C

ELECTRICAL CHARACTERISTICS $(T_{case} = 25^{\circ}C)$

STATIC

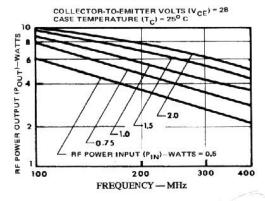
			2N3375		5	2N3632			2	N373	3	Unit
Symbol	Test	Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
ВУсво	I _C = 0.5mA	V _{BE} = 0	65			65			65			٧
BV _{CEO}	I _C = 200mA	I _B = 0	40			40			40			٧
BV _{EBO}	I _E = 0.25mA	I _C = 0	4	(I _E = ().1mA)	4			4			٧
ICEO	V _{CB} = 30V	I _E = 0			0.1			0.25	*	G	0.25	mΑ
H _{FE}	V _{CE} = 5V	I _C = 250mA	10			5	(I _C = 1A)		10			

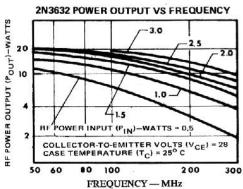
DYNAMIC

		200 19900	2	N337	5	2	N363	2	2	N373	3	Unit
Symbol	Test	Conditions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Po	F = 175MHz Class C	V _{CE} = 28V				13.5						W
Po	F = 400MHz	$V_{\rm CC} = 28V$	3						10			W
GP	F = 175MHz	$V_{\rm CC} = 28V$				5.8						dB
GР	F = 400MHz	$V_{\rm GC} = 28V$	4.8						4.0			dB
ης	F = 175MHz	V _{GG} = 28V				70		,				%
ηс	F = 400MHz	V _{CC} = 28V	40					250	45			%
Сов	F = 1MHz	V _{CB} = 30V			10			20			20	pF

APPLICATION INFORMATION (typical curves)

2N3375 POWER OUTPUT VS FREQUENCY

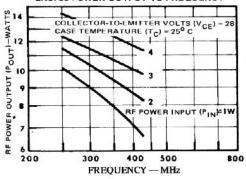




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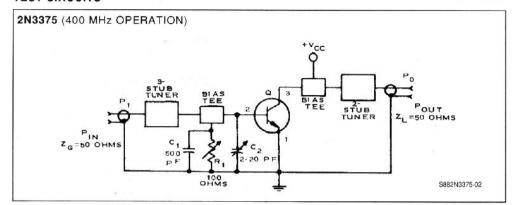
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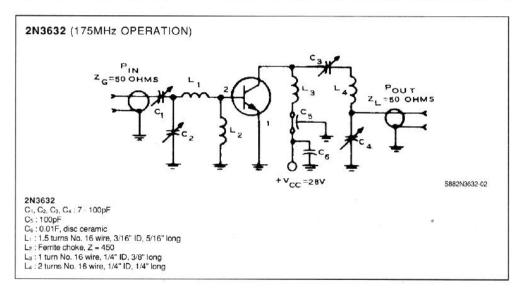
2N3733 POWER OUTPUT VS FREQUENCY

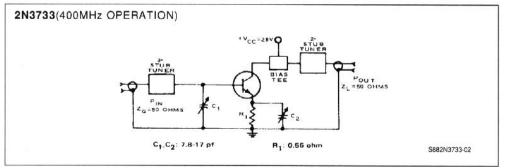


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TEST CIRCUITS



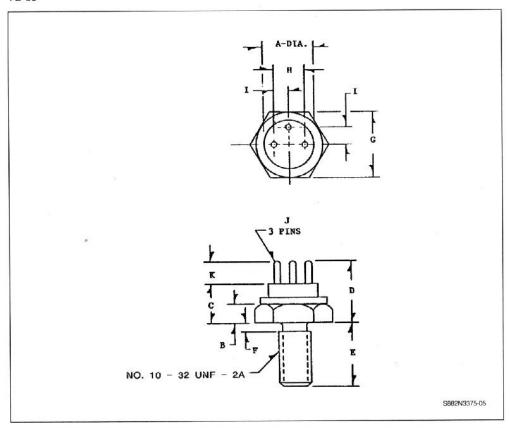




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PACKAGE MECHANICAL DATA

TO 60



	Minimum Inches	Maximum Inches
A	.320	.340
В	.110	.135
С	.245	.300
D	.400	.450
E	.420	.455
Е	.140	.160

	Minimum Inches	Maximum Inches
F		.078
G	.420	.440
н	.190	.210
1	.095	.105
J	.030	.046
K	.140	.160

This datasheet has been downloaded from:

www. Data sheet Catalog.com

Datasheets for electronic components.